```
? ds
Set Items Description
S1 5901240 S PRESSURE? OR PIEZO? OR PEIZO?
S2 2952994 S SENSOR? OR TRANSMITTER? OR TRANSMITTING?
S3 1234441 S HOUSING OR CASING OR ENCASING OR ENCLOSURE?
S4
    204887 S DIAPHRAGM?
S5 4082414 S FLUID?
     57652 S MICRO()MECHANICAL? OR MICROMECHANICAL?
    9048021 S CAVITY OR CAVITIES OR OPENING? OR HOLE? ? OR GAP? ? OR CHANNEL? OR CONDUIT? OR
S7
PATH??
     12586 S MICROREACT? OR MICRO()REACT?
S8
    131171 S S1(2N)S2
S9
       32 S S9 AND S3 AND S6
.S10
S11
       14 S S10 AND (S7 OR S4)
       13 RD (unique items)
S12
S13
      9977 S S9 AND S4
S14
      209 S S6 AND S13
       7 S S5 AND S14
S15
       7 S S15 NOT S12
S16
S17
       6 RD (unique items)
S18 113503 S S7(4N)S5
S19<sup>°</sup>
     33934 S S18 AND S1
S20
       39 S S19 AND S6
S21
       6 S S20 AND S4
S22 4 RD (unique items)
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? show files

[File 2] INSPEC 1898-2006/Mar W4

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[File 6] **NTIS** 1964-2006/Mar W4

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[File 8] Ei Compendex(R) 1970-2006/Mar W4

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[File 25] Weldasearch 19662006/Mar

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[File 34] SciSearch(R) Cited Ref Sci 1990-2006/Mar W4

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[File 36] MetalBase 1965-20060403

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[File 65] Inside Conferences 1993-2006/Apr 04

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[File 92] IHS Intl.Stds.& Specs. 1999/Nov

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[File 94] JICST-EPlus 1985-2006/Jan W2

(c)2006 Japan Science and Tech Corp(JST). All rights reserved.

[File 95] TEME-Technology & Management 1989-2006/Apr W1

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[File 99] Wilson Appl. Sci & Tech Abs 1983-2006/Mar

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[File 103] Energy SciTec 1974-2006/Mar B2

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[File 104] AeroBase 1999-2006/Mar

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[File 144] Pascal 1973-2006/Mar W2

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[File 239] Mathsci 1940-2006/May

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[File 434] SciSearch(R) Cited Ref Sci 1974-1989/Dec

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[File 647] CMP Computer Fulltext 1988-2006/Apr W4

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[File 315] ChemEng & Biotec Abs 1970-2006/Mar

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[File 347] JAPIO Dec 1976-2005/Dec(Updated 060404)

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[File 350] **Derwent WPIX** 1963-2006/UD,UM &UP=200622

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*File 350: For more current information, include File 331 in your search. Enter HELP NEWS 331 for details.

[File 31] World Surface Coatings Abs 1976-2006/Apr

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[File 248] PIRA 1975-2006/Mar W2

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[File 23] CSA Technology Research Database 1963-2006/Mar

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[File 33] Aluminium Industry Abstracts 1966-2006/Mar

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[File 335] Ceramic Abstracts/World Ceramics Abstracts 1966-2006/Mar

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[File 294] ONTAP(R) SciSearch(R) Cited Ref Science

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[File 954] Ei EnCompassLit(TM) 1965-2006/Apr W1

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*File 954: For disclaimer, type HELP NEWS 954. Alert feature enhanced for multiple files, etc. See HELP ALERT.

[File 953] Ei EnCompassPat(TM) 1964-200613

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10/9/1 (Item 1 from file: 350) Links
Derwent WPIX
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             **Image available**
015953677
WPI Acc No: 2004-111518/200412
XRPX Acc No: N04-088805
  Micromechanical pressure transducer has isolating membrane
  as region of thinner wall joined on one side to membrane type
 pressure sensor and exposed on other side to fluid with
  pressure to be measured
Patent Assignee: FIRST SENSOR TECHNOLOGY GMBH (FIRS-N); SIEMENS AG (SIEI )
Inventor: KRAUSE P; STECKENBORN A; KRAUSSE P
Number of Countries: 031 Number of Patents: 002
Patent Family:
                             Applicat No
                                             Kind
                                                    Date
                                                             Week
Patent No
              Kind
                     Date
                             EP 200390196
                                                  20030702
                                                            200412
               A1
                   20040121
                                              Α
EP 1382952
DE 10232721
               A1
                   20040212
                             DE 1032721
                                              Α
                                                  20020716
                                                            200413
Priority Applications (No Type Date): DE 1032721 A 20020716
Patent Details:
                                      Filing Notes
Patent No Kind Lan Pg
                         Main IPC
EP 1382952
              A1 G
                     8 G01L-009/00
   Designated States (Regional): AL AT BE BG CH CY CZ DE DK EE ES FI FR GB
   GR HU IE IT LI LT LU LV MC MK NL PT RO SE SI SK TR
              Α1
DE 10232721
                       G01L-009/02
Abstract (Basic): EP 1382952 A1
        NOVELTY - The device has a micromechanical housing (11) with
    a cavity (16) for a fluid whose pressure is to be measured to which a
    membrane type pressure sensor (12) is attached in
    micromechanical structural manner. An isolating membrane (22) in the
    housing is formed as a region of thinner wall joined on one side
    to the pressure sensor and exposed on its other side to
    the fluid with the pressure to be measured.
        USE - For pressure sensing.
        ADVANTAGE - Simple manufacture and operation.
        DESCRIPTION OF DRAWING(S) - The drawing shows a schematic
    representation of an inventivé micromechanical pressure
    transducer with a sensor mounted using flip-chip technology
        housing (11)
        cavity (16)
       membrane type pressure sensor (12)
        isolating membrane (22)
        base substrate (13)
        pp; 8 DwgNo 1/2
Title Terms: PRESSURE; TRANSDUCER; ISOLATE; MEMBRANE; REGION; THINNER; WALL
  ; JOIN; ONE; SIDE; MEMBRANE; TYPE; PRESSURE; SENSE; EXPOSE; SIDE; FLUID;
  PRESSURE; MEASURE
Derwent Class: S02; U12; V06
International Patent Class (Main): G01L-009/00; G01L-009/02
File Segment: EPI
```

Manual Codes (EPI/S-X): S02-F04B; U12-B03F1A; V06-L03

20/9/5 (Item 1 from file: 350) **Links**

Derwent WPIX

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017532999 **Image available** WPI Acc No: 2006-044239/200605

XRAM Acc No: C06-016765 XRPX Acc No: N06-037822

Display apparatus for providing immersive input display in monocular encasing, has display sharing optical path with eyecup, monocular, housing the display, and shutter sharing optical path with display and opens upon deformation of eyecup

Patent Assignee: BURNETT K (BURN-I); DURBIN J (DURB-I); SCHUETTE L (SCHU-I)

; TREMPER D (TREM-I)

Inventor: BURNETT K; DURBIN J; SCHUETTE L; TREMPER D Number of Countries: 001 Number of Patents: 001

Patent Family:

Patent No Kind Date Applicat No Kind Date Week
US 20050270251 A1 20051208 US 2004863847 A 20040603 200605 B

Priority Applications (No Type Date): US 2004863847 A 20040603

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

US 20050270251 A1 12 G09G-005/00

Abstract (Basic): US 20050270251 A1

NOVELTY - A display apparatus comprises a deformable eyecup; a display sharing an optical path with the eyecup; a monocular housing the display; and a shutter sharing the optical path with the eyecup and the display, where the shutter opens upon deformation of the eyecup.

USE - The apparatus is used for providing an immersive input display in a monocular **encasing**. The monocular can be connected to a system with a video graphics array, National Television System Committee, or equivalent output. The monocular can be applied to fire and rescue as well as police activities, where environmental awareness as well as access to computer data is useful. The monocular is also used to display the situational awareness software used by many emergency agencies while not revealing the user's presence in the immediate surroundings or removing the user's awareness of the immediate surroundings.

ADVANTAGE - The apparatus minimizes or eliminates light emission from the display, as well as inhibits or prevents ambient light from affecting visibility of the display.

DESCRIPTION OF DRAWING(S) - The figure is a block diagram of a display apparatus.

pp; 12 DwgNo 1/7

Technology Focus:

TECHNOLOGY FOCUS - ELECTRONICS - Preferred Component: The shutter comprises a mechanical iris, a liquid crystal shutter, a micro-mechanical micro-shutter array, and/or a shutter comprising flaps that flex upon the deformation. The apparatus further comprises a

pressure sensor communicating with eyecup and the shutter such that the deformation electrically actuates the iris. The display comprises a micro-display comprising an organic light emitting display, a liquid crystal on silicon display, a transmissive display, a transreflective display, a reflective display, a plasma display, a digital light processing display, and/or a scanned-beam display. The apparatus further comprises a lens sharing the optical path with the shutter and the display. The apparatus further comprises at least one of a focus slide and a focus ring for adjusting a distance between the lens and the display; a wireless receiver for receiving display data and sending the display data to the display; one of a wired connection and a wireless transceiver for receiving display data and sending the display data to the display; and at least one of a pointer controller, a scroll wheel, a touch pad, a mouse button, and a keypad for controlling the display data.

POLYMERS - Preferred Component: The eyecup comprises rubber, neoprene, plastic, and/or pleated material

Title Terms: DISPLAY; APPARATUS; INPUT; DISPLAY; MONOCULAR; ENCASED;

DISPLAY; SHARE; OPTICAL; PATH; MONOCULAR; HOUSING; DISPLAY;

SHUTTER; SHARE; OPTICAL; PATH; DISPLAY; OPEN; DEFORM

Derwent Class: A97; P85; S02; T04; W03; W05; W07

International Patent Class (Main): G09G-005/00

File Segment: CPI; EPI; EngPI

Manual Codes (CPI/A-N): A12-E11; A12-L03

Manual Codes (EPI/S-X): S02-F04B; T04-H03C9; W03-A09A; W03-A18A; W05-E07;

W07-G

Polymer Indexing (PS):

^{*001* 2004;} R01079 G0828 G0817 D01 D12 D10 D51 D54 D56 D58 D69 D84 C1 7A; H0000; P0328; P0340

^{*002* 2004;} H0124-R

^{*003* 2004;} Q9999 Q8264-R; ND01; K9416; Q9999 Q7512-R; K9905; Q9999 Q9029

20/9/7 (Item 3 from file: 350) Links

Derwent WPIX

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017220692 **Image available**
WPI Acc No: 2005-544310/200556

XRAM Acc No: C05-164905 XRPX Acc No: N05-445989

Wrapping of semiconductor pastilles to form structures for micromechanical devices incorporating a membrane, notably for pressure sensors

Patent Assignee: BOSCH GMBH ROBERT (BOSC); BENZEL H (BENZ-I); GUENSCHEL R

(GUEN-I); HAAG F (HAAG-I); PINTER S (PINT-I); WEIBLEN K (WEIB-I)

Inventor: BENZEL H; GUENSCHEL R; HAAG F; PINTER S; WEIBLEN K; GUNSCHER R;
HARK F

Number of Countries: 004 Number of Patents: 004

Patent Family:

Kind Date Patent No Applicat No Kind Date Week FR 2865575 A1 20050729 FR 200550168 Α 20050120 200556 B 20050121 US 20050186703 A1 20050825 US 200541157 Α 20040123 DE 102004003413 A1 20050811 DE 102004003413 A 20050804 JP 200515924 20050124 JP 2005210131 A Α 200556

Priority Applications (No Type Date): DE 102004003413 A 20040123

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

FR 2865575 A1 32 H01L-021/56 US 20050186703 A1 H01L-021/50 DE 102004003413 A1 H01L-021/52 JP 2005210131 A 16 H01L-023/02

Abstract (Basic): FR 2865575 A1

NOVELTY - Wrapping of semiconductor pastilles comprises:

- (a) production of a semiconductor pastille (5) with a first membrane zone (55);
- (b) installation of a cover (10) above the membrane zone leaving behind the membrane zone;
- (c) installation of the semiconductor pastille on a mounting frame (1);
- (d) realisation of a moulded **casing** (20) around the semiconductor pastille and of at least one partial zone of the mounting frame in order to wrap the semiconductor pastille.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for a semiconductor pastille produced.

USE - For wrapping a semiconductor pastille to form a semiconductor pastille structure for a **micromechanical** device incorporating a **pressure sensor**.

ADVANTAGE - The invention allows moulding or injection around the semiconductor pastille with a membrane zone to form a **casing** similar to that used for integrated circuits, which are simple and economic to fabricate. The cover above the membrane zone also mechanically reinforces the membrane zone whilst protecting against the

moulded mass. Since the cover is of silicon it has the same dilation coefficient as the semiconductor pastille which leads to a lower temperature effect in the output signal. It also eliminates the need for a passivation gel on the membrane thus providing a lower transverse sensitivity with respect to accelerations and more significant application pressures.

DESCRIPTION OF DRAWING(S) - The figure shows the wrapping of a semiconductor pastille according to the invention and shows a cross-sectional view of the corresponding semiconductor pastille. structure.

```
Mounting frame; (1)
Mounting frame passage; (2)
Semiconductor pastille; (5)
Cover; (10)
Glass sealing layer; (11)
Moulded casing; (20)
Passage; (21)
Piezoelectric resistances; (51)
Integrated circuit; (52)
Liaison strap; (53)
Membrane; (55)
Cavity; (58)
Lateral zone of pastille; (59)
Liaison wire; (60)
Cavity; (65)
Soldering layer; (70)
Glass base; (140)
Piercing. (141)
pp; 32 DwgNo 1/9
```

Technology Focus:

TECHNOLOGY FOCUS - CERAMICS AND GLASS - The cover is preferably made of silicon to provide the same dilation coefficient as that of the semiconductor pastille.

Title Terms: WRAP; SEMICONDUCTOR; PASTILLE; FORM; STRUCTURE; DEVICE; INCORPORATE; MEMBRANE; NOTABLY; PRESSURE; SENSE

Derwent Class: L03; Q68; S02; U11; U12

International Patent Class (Main): H01L-021/50; H01L-021/52; H01L-021/56; H01L-023/02

International Patent Class (Additional): B81B-003/00; B81C-001/00;

B81C-003/00; G01L-009/00; H01L-021/60

File Segment: CPI; EPI; EngPI

Manual Codes (CPI/A-N): L04-C21; L04-E10

Manual Codes (EPI/S-X): S02-F04B3; U11-C18C; U12-B03E; U12-B03F1

20/9/8 (Item 4 from file: 350) Links

Derwent WPIX

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017162285 **Image available**
WPI Acc No: 2005-486631/200549

XRPX Acc No: N05-396103

Micromechanical component manufacturing method e.g.

for micromechanical sensor, involves applying printed conductor to walls of cavity on substrate back

Patent-Assignee: BOSCH GMBH ROBERT (BOSC); BENZEL H (BENZ-I); FINKBEINER

S (FINK-I); GONSKA J (GONS-I); SCHELLING C (SCHE-I) Inventor: BENZEL H; FINKBEINER S; GONSKA J; SCHELLING C

Number of Countries: 002 Number of Patents: 002

Patent Family:

Patent No Kind Date Applicat No Kind Date Week US 20050133880 A1 20050623 US 200416617 Α 20041217 200549 B DE 10359217 A1 20050728 DE 10359217 Α 20031217 200549

Priority Applications (No Type Date): DE 10359217 A 20031217

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

US 20050133880 A1 9 G02B-026/00 DE 10359217 A1 B81B-003/00

Abstract (Basic): US 20050133880 A1

NOVELTY - A printed conductor (120) is applied to the walls of a **cavity** (140) on the substrate back (160), after forming an insulation layer (200). A printed conductor (110) is applied onto substrate front (150). A circuit element (220) formed at the substrate front is electrically connected to the printed conductor at substrate back by through-plating (130).

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for micromechanical component.

USE - For manufacturing micromechanical component (claimed)

e.g. micromechanical sensor including manifold sensor

element like pressure sensor, air mass sensor,

acceleration sensor, yaw rate sensor in integrated sensor system.

ADVANTAGE - The micromechanical components can be easily

arranged inside a **housing**, since there is no complex wiring from one side of the component to the other side.

DESCRIPTION OF DRAWING(S) - The figure depicts a cross-sectional view explaining **micromechanical** component manufacture.

substrate (100)

printed conductors (110,120)

through-plating (130)

cavity (140)

substrate front (150)

substrate back (160)

insulation layer (200)

circuit element (220)

pp; 9 DwgNo 2/5

Technology Focus:

TECHNOLOGY FOCUS - INORGANIC CHEMISTRY - The printed conductor is electrically insulated from the substrate by the insulation layer containing silicon oxide (SiOx) or silicon nitride.

ORGANIC CHEMISTRY - The printed conductor is electrically insulated from the substrate by the insulation layer containing silicon oxide (SiOx) or silicon nitride.

Title Terms: COMPONENT; MANUFACTURE; METHOD; SENSE; APPLY; PRINT; CONDUCTOR ; WALL; CAVITY; SUBSTRATE; BACK

Derwent Class: P81; Q68; S02; U12; V06

International Patent Class (Main): B81B-003/00; G02B-026/00

International Patent Class (Additional): B81C-001/00

File Segment: EPI; EngPI

Manual Codes (EPI/S-X): S02-C01F1; S02-F04B3; S02-G03; U12-B03E; U12-B03F1A

; V06-L02A; V06-L03

20/9/9 (Item 5 from file: 350) Links

Derwent WPIX

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016963041 **Image available**
WPI Acc No: 2005-287353/200530

XRAM Acc No: C05-089447 XRPX Acc No: N05-235451

Fabrication of a micro-mechanical sensor

incorporating a sensor element and a working circuit for a wide range of data acquisition applications

Patent Assignee: BOSCH GMBH ROBERT (BOSC); BENZEL H (BENZ-I); SCHAEFER F

(SCHA-I); SCHELLING C (SCHE-I)

Inventor: BENZEL H; SCHAEFER F; SCHELLING C

Number of Countries: 003 Number of Patents: 003

Patent Family:

Patent No Kind Date Applicat No Kind Date Week FR 2860779 A1 20050415 FR 200452287 Α 20041007 200530 B DE 10347215 20050512 DE 10347215 A1 Α 20031010 200532 US 20050115321 A1 20050602 US 2004958014 Α 20041004 200537

Priority Applications (No Type Date): DE 10347215 A 20031010

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

FR 2860779 A1 19 B81C-001/00 DE 10347215 A1 B81C-001/00 US 20050115321 A1 G01N-025/00

Abstract (Basic): FR 2860779 A1

NOVELTY - A micro-mechanical sensor is fabricated incorporating a component (100) of a first material with at least one sensor zone having a sensor element, a part of a working circuit (130) and first and second sides. The first side incorporates the sensor element and the second side incorporates the working circuit. At least a part of the sensor zone and/or the working circuit are realised by a micro-mechanical machining in the first material.

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for the micro-mechanical sensor fabricated in this manner.

USE - The invention is used for the fabrication of micro-mechanical sensors applicable for the measurement of pressure or temperature or air mass or air quality or dew point or gas humidity or the chemical composition of a gas or liquid or acceleration or speed of rotation or thermal conductivity (all claimed).

ADVANTAGE - The invention allows the fabrication of micromechanical sensors for a wide range of applications. It provides economic advantages and surface gains in the fabrication of the sensors. Simultaneous treatment of several sides of the component reduce the fabrication time and the spatial separation of the working circuit and the sensor zone leads to a setting economy for the upper surface effectively needed and that will be exposed to the substance to be measured.

DESCRIPTION OF DRAWING(S) - The drawing illustrates a form of

```
pressure sensor according to the invention.
        First component; (100)
        Part of working circuit; (130)
        Linkage; (410).
        Conducting track; (450)
        Second component; (500)
        Casing; (510)
        Cavity; (520)
        Oscillating structure; (530)
        Sensor zone; (540)
        Intermediate layer. (550)
        pp; 19 DwgNo 5/5
Technology Focus:
        TECHNOLOGY FOCUS - ELECTRONICS - The sensor element may be a
   membrane or a resistive structure or piezo-sensitive resistance layers
    or a temperature sensor or an electrode device or an oscillating
    structure (claimed).
Title Terms: FABRICATE; MICRO; MECHANICAL; SENSE; INCORPORATE; SENSE;
  ELEMENT; WORK; CIRCUIT; WIDE; RANGE; DATA; ACQUIRE; APPLY
Derwent Class: L03; Q68; S02; S03; U11; U12; V06
International Patent Class (Main): B81C-001/00; G01N-025/00
International Patent Class (Additional): B81B-003/00; B81B-007/00;
 G01K-007/00; G01L-009/00; G01N-007/00; G01P-015/00; H01L-021/461;
 H01L-029/84
File Segment: CPI; EPI; EngPI
Manual Codes (CPI/A-N): L03-G10A; L04-E10
Manual Codes (EPI/S-X): S02-F04B1; S02-F04B2; S03-B01C; S03-E01A; S03-E02X;
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U11-C18C; U12-B03F1A; V06-L02A; V06-L03; V06-L10

12/9/11 (Item 7 from file: 350) Links Derwent WPIX (c) 2006 Thomson Derwent. All rights reserved. **Image available** 013516966 WPI Acc No: 2001-001172/200101 XRPX Acc No: N01-000963 Micromechnical or micromechanical-electronic component device - has channel formed in surface of micromechanical of micromechanical-electronic component for isolating outer region attached to casing of device from its inner region Patent Assignee: SIEMENS AG (SIEI .) Inventor: AIGNER R; KAPELS H; MARKSTEINER S; OPPERMANN K Number of Countries: 025 Number of Patents: 001 Patent Family: Patent No Kind Date Applicat No Kind Date EP 1055921 A2 20001129 EP 2000109364 Α 20000502 200101 B Priority Applications (No Type Date): DE 1024084 A 19990526 Patent Details: Patent No Kind Lan Pg Main IPC Filing Notes EP 1055921 A2 G 5 G01L-019/00 Designated States (Regional): AL AT BE CH CY DE DK ES FI FR GB GR IE IT LI LT LU LV MC MK NL PT RO SE SI Abstract (Basic): EP 1055921 A The device has a casing in which at least one micromechanical or micromechanical-electronic component (2) is supported. The surface of the component has at least one channel (3) dividing it into an inner region (22) and an outer region mechanically secured to the casing. The channel provides mechanical isolation between the outer region and the inner region, so that deformation of the outer region caused by the casing is not transmitted to the inner region. USE - Device is used as acceleration sensor or pressure sensor. ADVANTAGE -Inner region of micromechanical or micromecha. Title Terms: ELECTRONIC; COMPONENT; DEVICE; CHANNEL; FORMING; SURFACE; ELECTRONIC; COMPONENT; ISOLATE; OUTER; REGION; ATTACH; CASING; DEVICE; INNER; REGION

Derwent Class: S02; U12

File Segment: EPI

International Patent Class (Main): G01L-019/00

Manual Codes (EPI/S-X): S02-F04B3; S02-F04E; S02-G03; U12-B03F

12/9/12 (Item 8 from file: 350) Links

Derwent WPIX

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013076559 **Image available**
WPI Acc No: 2000-248431/200022

XRAM Acc No: C00-075318 XRPX Acc No: N00-186011

Semiconductor micromechanical sensor, e.g. a pressure sensor, is fixed in a housing by a gel to provide an elastic, viscous or flexible bond and long term protection

Patent Assignee: SIEMENS AG (SIEI)

Inventor: WILDGEN A

Number of Countries: 003 Number of Patents: 004

Patent Family:

Da	tent No	Kind	Date	Applicat No	Kind	Date	Week	
Pa	cent No	KING	Date	Applicat No .	KING	Date	MEGY	
FR	2783048	A1	20000310	FR 9910868	Α	19990827	200022	В
DE	19840829	À1	20000323	DE 198040829	Α	19980907	200022	
US	6350630	B1	20020226	US 99390166	Α	19990907	200220	
DE	19840829	B4	20051020	DE 198040829	Α	19980907	200569	

Priority Applications (No Type Date): DE 198040829 A 19980907

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

FR 2783048 A1 14 G01L-019/14
DE 19840829 A1 G01L-019/14
US 6350630 B1 H01L-021/48
DE 19840829 B4 G01L-019/14

Abstract (Basic): FR 2783048 A1

NOVELTY - Semiconductor micromechanical sensor (12) fixed in a housing (11) by (a) positioning sensor on a seating surface (112) in a housing recess (111); (b) simultaneously forming an electrical connection (14) between the sensor and electrical contact (15) on the housing and fixing the sensor to the housing by pressure reduction through a conduit (114); and (c) filling recess with a fixing gel (13).

DETAILED DESCRIPTION - An INDEPENDENT CLAIM is also included for a sensor structure produced by the above process.

USE - For housing a semiconductor micromechanical sensor such as a pressure sensor.

ADVANTAGE - The gel produces an elastic, viscous or flexible bond between the sensor chip and the **housing** to avoid affecting the sensor characteristics, provides long term protection of the sensor from its environment and avoids the need for use of a support, an adhesive and a protective membrane so that manufacture is simplified and is more economical.

.DESCRIPTION OF DRAWING(S) — The drawing shows a sensor structure according to the invention.

Housing (11) Sensor chip (12) Gel (13)
Electrical connection (14)
Electrical contact (15)
Recess (111)
Seating surface (112)
Pressure reduction conduit (114)
pp; 14 DwgNo 1/3

Technology Focus:

TECHNOLOGY FOCUS - POLYMERS - Preferred Gel: The gel is a fluorinated silicone gel.

Title Terms: SEMICONDUCTOR; SENSE; PRESSURE; SENSE; FIX; HOUSING; GEL; ELASTIC; VISCOSITY; FLEXIBLE; BOND; LONG; TERM; PROTECT

Derwent Class: A88; S02

International Patent Class (Main): G01L-019/14; H01L-021/48

International Patent Class (Additional): H01L-023/02; H01L-029/84

File Segment: CPI; EPI

Manual Codes (CPI/A-N): A06-A00E2; A12-E13

Manual Codes (EPI/S-X): S02-F04E

Polymer Indexing (PS):

001 018; F- 7A; S9999 S1365; P1445-R F81 Si 4A; M9999 M2255 M2222

002 018; ND01; Q9999 Q7874; B9999 B3930-R B3838 B3747; B9999 B3554-R; B9999 B4035 B3930 B3838 B3747; K9483-R; K9676-R

003 018; F- 7A; H0157

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22/9/4 (Item 2 from file: 350) Links
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Derwent WPIX

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011268974 **Image available**
WPI Acc No: 1997-246877/199723
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XRPX Acc No: N97-203510

Micro mechanically manufactured flow

restriction system with passage opening - is formed in first main surface of substrate with duct formed in second main surface of substrate in fluid communication with passage opening also with

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diaphragm
Patent Assignee: FRAUNHOFER GES FOERDERUNG ANGEWANDTEN (FRAU
Inventor: WOIAS P
Number of Countries: 020 Number of Patents: 007
Patent Family:
Patent No
                              Applicat No
                                              Kind
                                                     Date
                                                              Week
              Kind
                     Date
                   19970430
                              DE 97U2001418
                                                   19970128
                                                             199723
DE 29701418
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DE 19650116
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WO 9825110
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EP 943076
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US 6263741
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                              WO 97EP6342
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                                                   19971113
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                              US 99319169
                                                   19990601
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Priority Applications (No Type Date): DE 1050116 A 19961203

Patent Details:

Patent No Kind Lan Pg Main IPC Filing Notes

DE 29701418 U1 14 G01F-001/40 DE 19650116 C1 6 G01F-001/40 WO 9825110 A1 G G01F-001/38

Designated States (National): JP US

Designated States (Regional): AT BE CH DE DK ES FI FR GB GR IE IT LU MC NL PT SE

EP 943076 A1 G G01F-001/38 Based on patent WO 9825110 Designated States (Regional): CH DE DK FR GB IT LI NL SE

EP 943076 B1 G · G01F-001/38 Based on patent WO 9825110

Designated States (Regional): CH DE DK FR GB IT LI NL SE DE 59701675 G G01F-001/38 Based on patent EP 943076

Based on patent WO 9825110

US 6263741 B1 G01F-001/38 Based on patent WO 9825110

Abstract (Basic): DE 29701418 U

The system has a passage opening (12) formed in the first main surface of the substrate (10), with a duct (16) formed in a second main surface of the substrate, communicating **fluidly** with the passage **opening**, also with a **diaphragm** (22). One **diaphragm**

electrode (26) at least is formed on the **diaphragm**. A cover system (30) is applied on the second main surface of the substrate, such that the **diaphragm** electrode together with the duct, define a flow resistance of the flow restriction system.

The cover system has a counter electrode (32) which spaced at a distance from the **diaphragm** electrode, lies opposite the same. In such a manner that the **diaphragm** electrode and the counter electrode define a capacitive **pressure** pick-up. A passage opening is formed in the cover system, which has fluid communication with the duct.

USE/ADVANTAGE - Liquid dosing field. Cost effective and simple micro mechanically manufactured flow restriction system, with at least one integrated pressure sensor.

Dwg.1/2

Title Terms: MICRO; MECHANICAL; MANUFACTURE; FLOW; RESTRICT; SYSTEM; PASSAGE; OPEN; FORMING; FIRST; MAIN; SURFACE; SUBSTRATE; DUCT; FORMING; SECOND; MAIN; SURFACE; SUBSTRATE; FLUID; COMMUNICATE; PASSAGE; OPEN; DIAPHRAGM

Derwent Class: 057; S02

International Patent Class (Main): G01F-001/38; G01F-001/40

International Patent Class (Additional): F15C-005/00; G01F-001/56;

G01L-007/08; G01L-009/12 File Segment: EPI; EngPI

Manual Codes (EPI/S-X): S02-C01A1; S02-C01B4